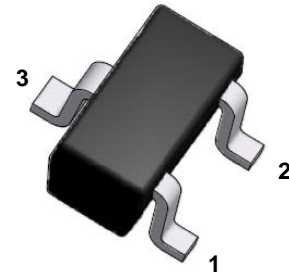


150mW SOT-523 SURFACE MOUNT Plastic Package NPN Silicon General Purpose Transistor

Green Product



SOT-523

Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

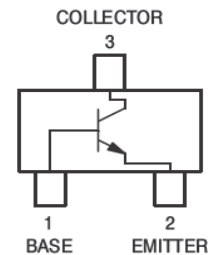
Symbol	Parameter	Value	Units
P_C	Collector Power Dissipation	150	mW
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	+150	$^\circ\text{C}$
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current - Continuous	100	mA

These ratings are limiting values above which the serviceability of the diode may be impaired.

Specification Features:

- Low $C_{ob} = 2.0\text{pF}$ (Typical)
- Low $V_{ce(sat)} < 0.4\text{V}$
- RoHS Compliant
- Green EMC
- Matte Tin(Sn) Lead Finish
- Weight: approx. 0.002g

Electrical Symbol:



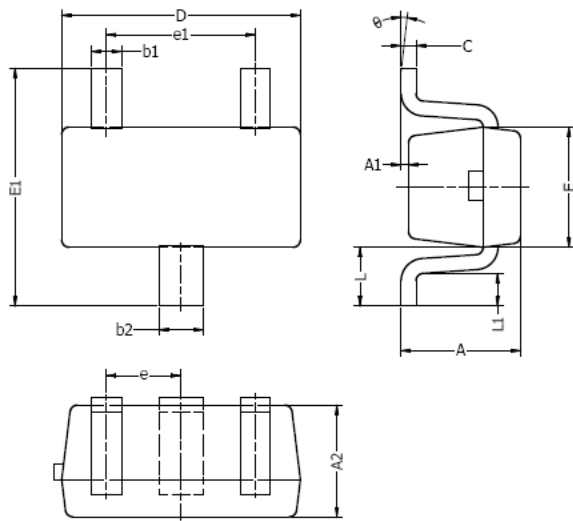
Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Limits			Unit
			Min	Typ	Max	
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C=50\mu\text{A}, I_E=0\text{A}$	50			Volts
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C=1\text{mA}, I_B=0\text{A}$	50			Volts
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E=50\mu\text{A}, I_C=0\text{A}$	5			Volts
I_{CBO}	Collector Cut-off Current	$V_{CB}=50\text{V}, I_E=0\text{A}$			0.1	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=5\text{V}, I_C=0\text{A}$			0.1	μA
h_{FE}	DC Current Gain	$V_{CE}=6\text{V}, I_C=1\text{mA}$	120		560	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=50\text{mA}, I_B=5\text{mA}$			0.4	Volts
f_T	Transition Frequency	$V_{CE}=5\text{V}, I_C=10\text{mA}$ $f=30\text{MHz}$		280		MHz
C_{OB}	Collector Output Capacitance	$V_{CB}=12\text{V}, I_E=0\text{A},$ $f=1\text{MHz}$		2.0		pF

Classification of h_{FE}

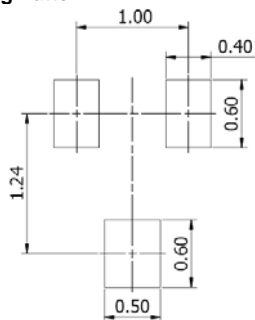
Rank	Q	R	S
Range	120 - 270	180 - 390	270 - 560
Marking	BQ	BR	BS

SOT-523 Package Outline



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.70	0.90	0.028	0.035
A1	0.00	0.10	0.000	0.004
A2	0.70	0.80	0.028	0.031
b1	0.15	0.25	0.006	0.010
b2	0.25	0.35	0.010	0.014
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
E1	1.45	1.75	0.057	0.069
e	0.50 TYP.		0.020 TYP.	
e1	0.90	1.10	0.035	0.043
L	0.40 REF.		0.016 REF.	
L1	0.10	0.30	0.004	0.012
θ	0°	8°	0°	8°

Typical Soldering Pattern:



NOTES:

1. Above package outline conforms to JEITA EAIJ ED-7500A SC-75A.
2. Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

NOTICE

The information presented in this document is for reference only. Tak Cheong reserves the right to make changes without notice for the specification of the products displayed herein.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tak Cheong Semiconductor Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

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